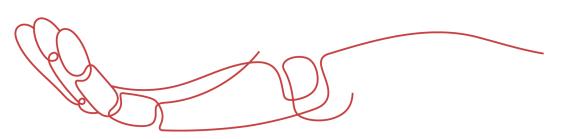




PRODUCT DATA SHEET



To learn more about JGSEMI, please visit our website at







Datasheet

Samples

Please note: Please check the JINGAO Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.jg-semi.cn. Please email any questions regarding the system integration to JINGAO_questions@jgsemi.com.

Unit: mm

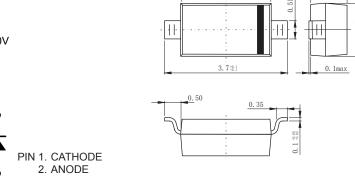
Schottky Barrier Diodes

■ Features

● Forward Voltage : VF=0.365V (TYP.)

● Forward Current : IF(AV)=1A

● Repetitive Peak Reverse Voltage : VRM=40V



SOD-123

■ Absolute Maximum Ratings Ta = 25°C

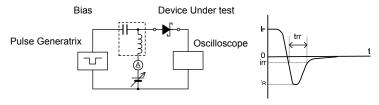
Parameter	Symbol	Rating	Unit	
Non-Repetitive Peak reverse voltage	Vrм	40	V	
DC Blocking Voltage	VR	30		
DC Forward Current	I _{F(AV)}	1	· A	
Peak forward surge current (Note.1)	IFSM	20		
Junction Temperature	TJ	125	$^{\circ}$	
Storage temperature range	Tstg	-55 to 150		

Note.1:Non continuous high amplitude 60Hz half-sine wave.

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Reverse breakdown voltage	VRM	IR= 100 uA	30			V
Forward voltage	VF	IF= 100m A		230	315	mV
		IF= 500mA		300	385	
		IF= 1 A		365	410	
Reverse voltage leakage current	lr	VR= 40 V		0.25	2	mA
Junction capacitance	Cj	VR= 1V, f= 1 MHz		150		pF
Reverse Recovery Time (Note.2)	trr	IF=IR=10mA , irr=1mA		41		ns

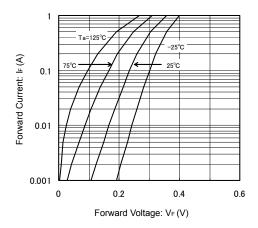
Note.2: trr measurement circuit.



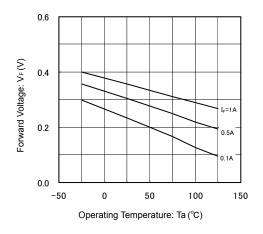


■ Typical Characterisitics

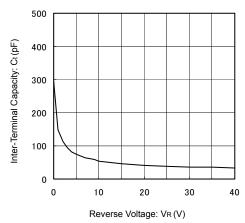
(1) Forward Current vs. Forward Voltage



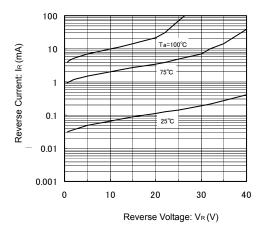
(3) Forward Voltage vs. Operating Temperature



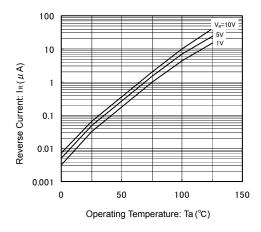
(5) Inter-Terminal Capacity vs. Reverse Voltage



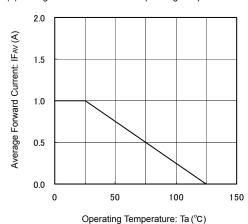
(2) Reverse Current vs. Reverse Voltage



(4) Reverse Current vs. Operating Temperature



(6) Average Forward Current vs. Operating Temperature





Attention

- 1, Any and all JGSEMI products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, orother applic ations whose failure can be reasonably expected to result in serious physical or material damage. Consult with your JGSEMI representative nearest you before using any JGSEMI products described or contained herein in such applications.
- 2,JGSEMI assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all JGSEMI products described or contained herein.
- 3, Specifications of any and all JGSEMI products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To ver ify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- 4,In the event that any or all JGSEMI products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported wit hout obtaining the export license from the authorities concerned in accordance with the above law.
- 5, No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanic al, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the pr ior written permission of JGSEMI Semiconductor CO., LTD.
- 6, Any and all information described or contained herein are subject to change without notice due to product technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the JGSEMI product that you Intend to use.